

## T494B107M006AT

**General Information** 

T494, Tantalum, MnO2 Tantalum, 100 uF, 20%, 6.3 VDC, SMD, MnO2, Molded, Low ESR, 1.5 Ohms, 3528, 2.1 mm, 0.8 mm

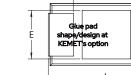
CATHODE (-) END VIEW



ANODE (+) END VIEW

ΗB - S -- | - S -— G -BOTTOM VIEW ٠A

SIDE VIEW



Click here for the 3D model.

Series	T494
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	107.45 mg
Shelf Life	156 Weeks
MSL	1

Dimensions		Spe
L	3.5mm +/-0.2mm	Cap
W	2.8mm +/-0.2mm	Tole
н	1.9mm +/-0.2mm	Volt
т	0.13mm REF	Tem
S	0.8mm +0.1/-0.3mm	Rate
F	2.2mm +/-0.1mm	Diss
A	1.9mm MIN	Failu
В	0.4mm +/-0.15mm	ESR
E	2.2mm REF	Ripp
G	1.8mm REF	
Р	0.5mm REF	Lea
R	1mm REF	
Х	0.1mm +/-0.1mm REF	

Specifications	
Capacitance	100 uF
Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	15% 120Hz 25C
Failure Rate	N/A
ESR	1.5 Ohms (100kHz 25C)
Ripple Current	238 mA (rms, 100kHz 25C), 214.2 mA (rms, 85C), 95.2 mA (rms, 125C)
Leakage Current	6.3 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

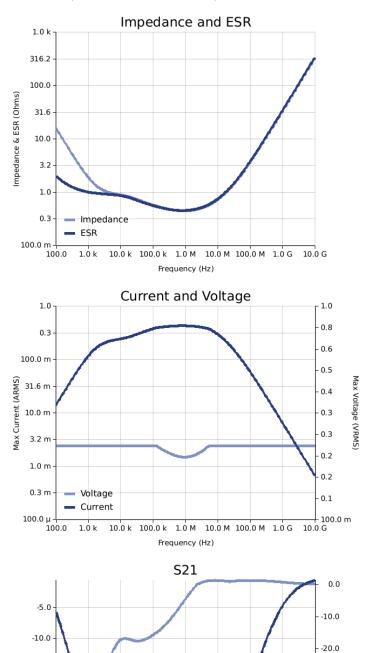
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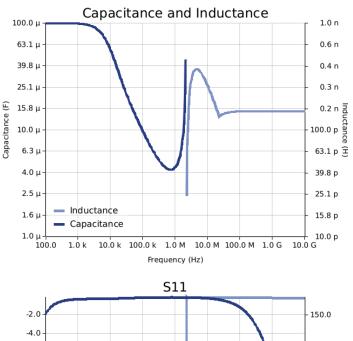


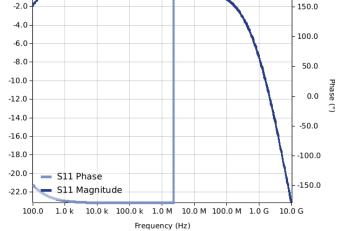
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## Simulations

For the complete simulation environment please visit K-SIM.







Magnitude (db)

-30.0 Phase

°

-40.0

-50.0

-60.0

100.0

Magnitude (db)

-15.0

-20.0

-25.0

-30.0

S21 Phase

1.0 k

S21 Magnitude

10.0 k 100.0 k 1.0 M 10.0 M 100.0 M 1.0 G 10.0 G

Frequency (Hz)



## These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated. The effects shown herein are based on measured data from a multiple part sample of the parts in question. Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance. The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.
  Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.